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BS270

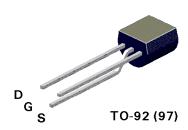
N-Channel Enhancement Mode Field Effect Transistor

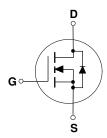
General Description

These N-Channel enhancement mode field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. They can be used in most applications requiring up to 500mA DC. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- 400mA, 60V. $R_{DS(ON)} = 2\Omega$ @ $V_{GS} = 10V$.
- High density cell design for low R_{DS(ON)}.
- Voltage controlled small signal switch.
- Rugged and reliable.
- High saturation current capability.





Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	BS270	Units
V _{DSS}	Drain-Source Voltage	60	V
V_{DGR}	Drain-Gate Voltage ($R_{gs} \leq 1M\Omega$)	60	V
V _{GSS}	Gate-Source Voltage - Continuous	±20	V
	- Non Repetitive (tp < 50µs)	±40	
I _D	Drain Current - Continuous	400	mA
	- Pulsed	2000	
P _D	Maximum Power Dissipation	625	mW
	Derate Above 25°C	5	mW/°C
T _J ,T _{STG}	Operating and Storage Temperature Range	-55 to 150	°C
T _L	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds	300	°C
THERMA	L CHARACTERISTICS		•
R _{eJA}	Thermal Resistacne, Junction-to-Ambient	200	°C/W

Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAI	RACTERISTICS	·					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{gs} = 0 \text{ V}, I_{D} = 10 \mu\text{A}$		60			V
DSS	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$				1	μΑ
			$T_{J} = 125^{\circ}C$			500	μΑ
GSSF	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$				10	nA
GSSF	Gate - Body Leakage, Reverse	$V_{gs} = -20 \text{ V}, V_{ds} = 0 \text{ V}$				-10	nA
ON CHAR	ACTERISTICS (Note 1)						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$		1	2.1	2.5	V
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{gs} = 10 \text{ V}, I_{D} = 500 \text{ mA}$			1.2	2	Ω
			T _J = 125°C		2	3.5	
		$V_{gs} = 4.5 \text{ V}, I_{D} = 75 \text{ mA}$			1.8	3	
V _{DS(ON)}	Drain-Source On-Voltage	$V_{GS} = 10 \text{ V}, I_{D} = 500 \text{ mA}$			0.6	1	V
		$V_{GS} = 4.5 \text{ V}, I_{D} = 75 \text{ mA}$			0.14	0.225	
D(ON)	On-State Drain Current	$V_{GS} = 10 \text{ V}, \ V_{DS} \ge 2 V_{DS(on)}$		2000	2700		mA
		$V_{\text{GS}} = 4.5 \text{ V}, \ V_{\text{DS}} \ge 2 \ V_{\text{DS(on)}}$		400	600		
g _{FS}	Forward Transconductance	$V_{DS} \ge 2 V_{DS(on)}, I_D = 200 \text{ mA}$		100	320		mS
DYNAMIC	CHARACTERISTICS						
C _{iss}	Input Capacitance	$V_{ps} = 25 \text{ V}, V_{qs} = 0 \text{ V},$ $f = 1.0 \text{ MHz}$			20	50	рF
C _{oss}	Output Capacitance				11	25	pF
C _{rss}	Reverse Transfer Capacitance				4	5	pF
SWITCHIN	G CHARACTERISTICS (Note 1)						
ton	Turn-On Time	$V_{DD} = 30 \text{ V}, \ I_{D} = 500 \text{ m A}, \ V_{GS} = 10 \text{ V}, R_{GEN} = 25 \Omega$				10	ns
off	Turn-Off Time					10	ns
DRAIN-SO	URCE DIODE CHARACTERISTICS AND	MAXIMUM RATINGS					
S	Maximum Continuous Drain-Source Diode Forward Current					400	mA
SM	Maximum Pulsed Drain-Source Diode Forward Current				2000	mA	
V_{SD}	Drain-Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_{S} = 400 \text{ mA}_{(Note 1)}$			0.88	1.2	V	

Note: 1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

Typical Electrical Characteristics

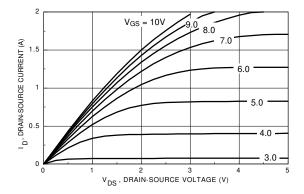


Figure 1. On-Region Characteristics.

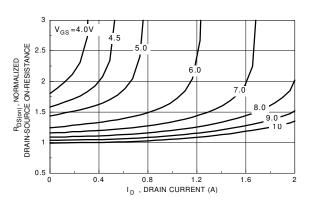


Figure 2. On-Resistance Variation with Gate Voltage and Drain Current.

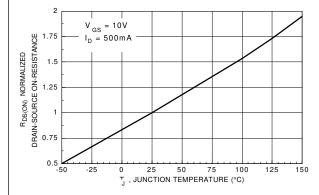


Figure 3. On-Resistance Variation with Temperature.

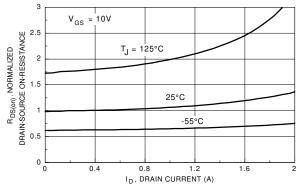


Figure 4. On-Resistance Variation with Drain Current and Temperature.

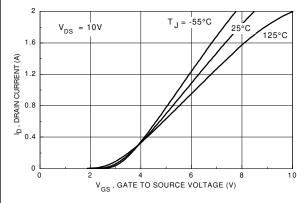


Figure 5. Transfer Characteristics.

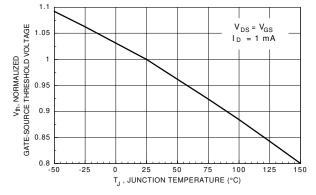


Figure 6. Gate Threshold Variation with Temperature.

Typical Electrical Characteristics (continued)

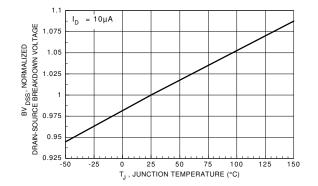


Figure 7. Breakdown Voltage Variation with Temperature.

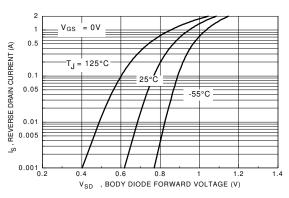


Figure 8. Body Diode Forward Voltage Variation with Current and Temperature.

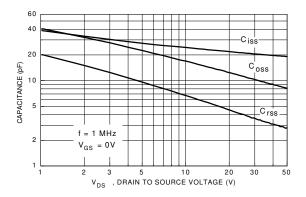


Figure 9. Capacitance Characteristics.

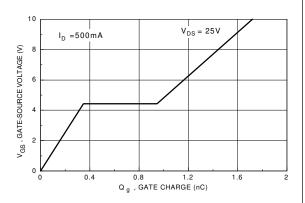


Figure 10. Gate Charge Characteristics.

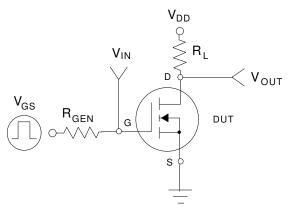


Figure 11. Switching Test Circuit.

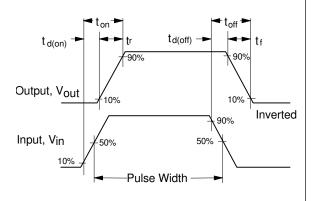


Figure 12. Switching Waveforms.

Typical Electrical Characteristics (continued)

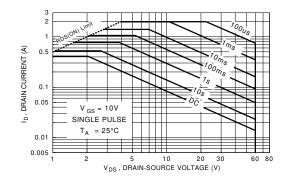


Figure 13. Maximum Safe Operating Area.

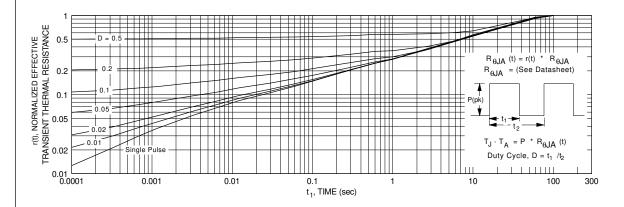


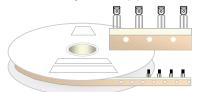
Figure 14. Transient Thermal Response Curve.

TO-92 Tape and Reel Data FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVR/418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z 2,000 Е D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** $\begin{array}{ll} \mbox{Unit weight} & = 0.22 \ \mbox{gm} \\ \mbox{Reel weight with components} & = 1.04 \ \mbox{kg} \\ \mbox{Ammo weight with components} & = 1.02 \ \mbox{kg} \\ \mbox{Max quantity per intermediate box} & = 10,000 \ \mbox{units} \\ \end{array}$ Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** TO-92 STANDARD STRAIGHT FOR: PKG 92, 94 (NON PROELECTRON NO EOL NO LEADCLIP 2.0 K / BOX SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

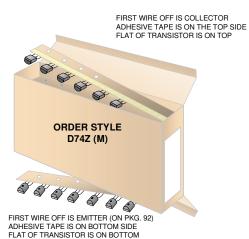


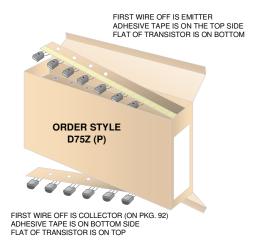
Style "A", D26Z, D70Z (s/h)

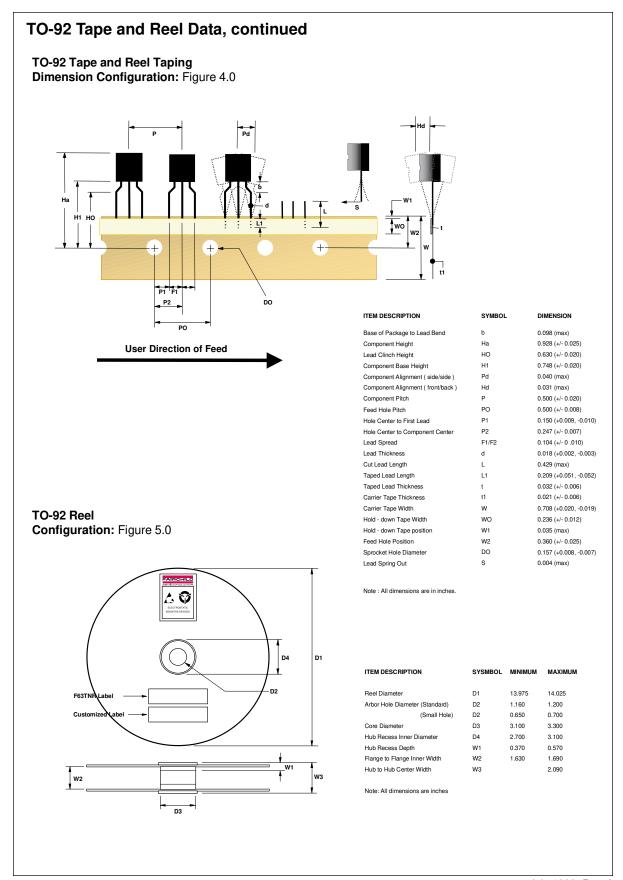
Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0



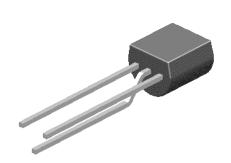


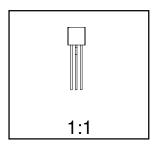


TO-92 Package Dimensions



TO-92; TO-18 Reverse Lead Form (J35Z Option) (FS PKG Code 92, 94, 96)

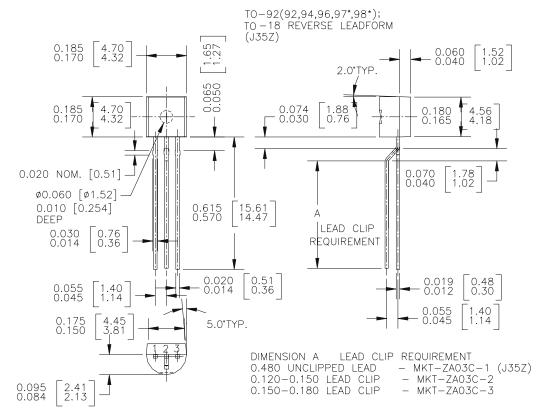




Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.22



Note: All package 97 or 98 transistors are leadformed to this configuration prior to bulk shipment. Order L34Z option if in-line leads are preferred on package 97 or 98.

^{*} Standard Option on 97 & 98 package code

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